

#### 140V PNP LOW SATURATION MEDIUM VOLTAGE TRANSISTOR IN SOT89

#### **Features**

- BV<sub>CEO</sub> > -140V
- I<sub>C</sub> = -3A High Continuous Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -75mV @ -0.5A
- $R_{sat}$  = 85m $\Omega$  for a Low Equivalent On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.05 grams (Approximate)

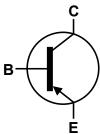
### **Application**

- Motor driving
- Line switching
- High side switches
- Subscriber line interference cards (SLIC)

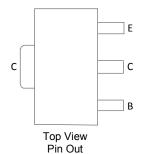




Top View



Device Symbol



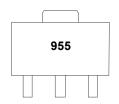
### Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTP2014ZTA	Standard	955	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain < 900ppm bromine, < 900ppm chlorine (< 1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



955 = Product Type Marking Code



# Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-140	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-3	А
Peak Pulse Current	I <sub>CM</sub>	-10	А

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) Linear Derating Factor	P <sub>D</sub>	1.5 12	W mW/°C
Power Dissipation (Note 6) Linear Derating Factor	PD	2.1 16.8	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>θJA</sub>	83	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>θJA</sub>	60	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

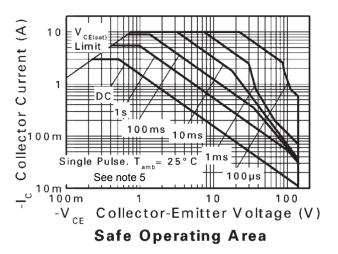
Notes:

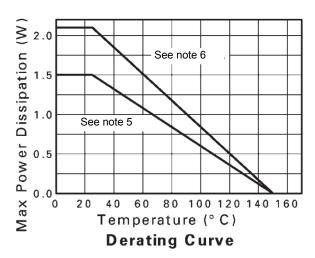
<sup>5.</sup> For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.

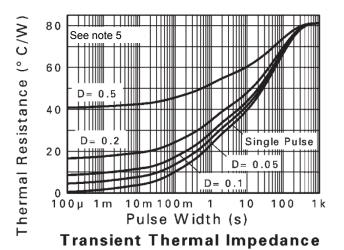
6. Same as note (5), except the device is mounted on 50mm x 50mm x 1.6mm single sided 1oz weight copper.

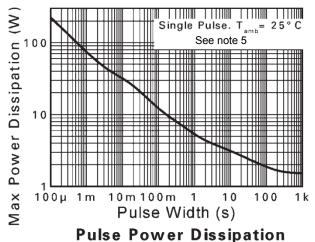


# **Thermal Characteristics and Derating Information**











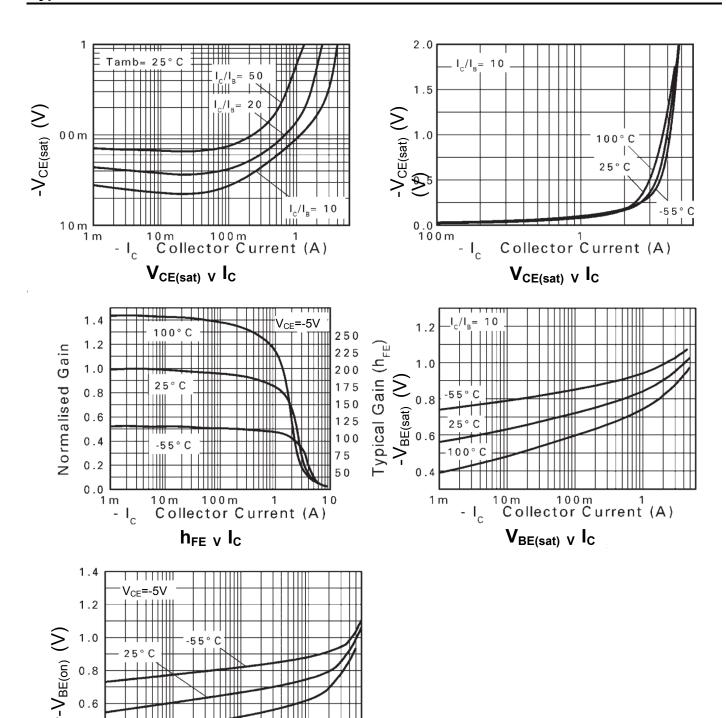
## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	-180	-200	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage	BV <sub>CER</sub>	-180	-200	_	V	$I_C = -1\mu A$ , RB $\leq 1k\Omega$
Collector- Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-140	-160	_	V	I <sub>E</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7.0	-8.0	_	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	_	-1 —	-20 -0.5	nΑ μΑ	V <sub>CB</sub> = -150V V <sub>CB</sub> = -150V, T <sub>A</sub> = +100°C
Collector Cutoff Current	I <sub>CER</sub> R≤1kΩ	_	-1 —	-20 -0.5	nA μA	V <sub>CB</sub> = -150V V <sub>CB</sub> = -150V, T <sub>A</sub> = +100°C
Emitter Cutoff Current	I <sub>EBO</sub>	_	-1	-10	nA	V <sub>EB</sub> = -6V
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE(sat)</sub>	_	-37 -50 -80 -255	-60 -75 -115 -330	mV	$I_C = -0.1A$ , $I_B = -5mA$ $I_C = -0.5A$ , $I_B = -50mA$ $I_C = -1A$ , $I_B = -100mA$ $I_C = -3A$ , $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(sat)</sub>	_	-970	-1010	mV	I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter Turn-On Voltage (Note 7)	V <sub>BE(on)</sub>	_	-800	-900	mV	I <sub>C</sub> = -3A, V <sub>CE</sub> = -5V
Static forward current transfer ratio (Note 7)	h <sub>FE</sub>	100 100 45 —	255 200 100 5	 300  	_	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -1A, V <sub>CE</sub> = -5V I <sub>C</sub> = -3A, V <sub>CE</sub> = -5V I <sub>C</sub> = -10A, V <sub>CE</sub> = -5V
Transitional Frequency	f⊤	_	120	_	MHz	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V, f = 50MHz
Output Capacitance	C <sub>obo</sub>	_	33	_	pF	V <sub>CB</sub> = -10V, f = 1MHz
Switching Time	t <sub>on</sub> t <sub>off</sub>	_	42 636	_	ns	$I_C = -1A$ , $V_{CC} = -50V$ , $I_B 1 = -I_B 2 = -100 \text{mA}$

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



### Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)



10m 100m 1 Collector Current (A)

0.6

0.4

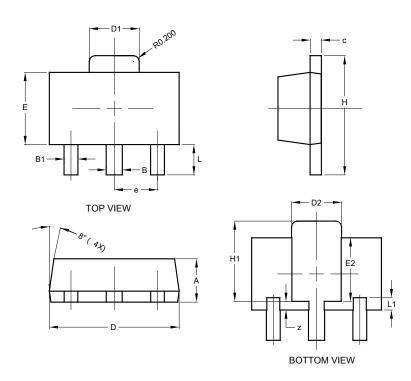
1 m



### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT89

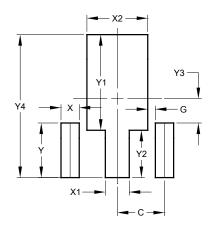


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	ı	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT89



Dimensions	Value (in mm)
С	1.500
G	0.244
Х	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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